

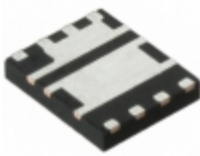
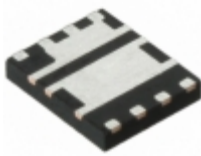
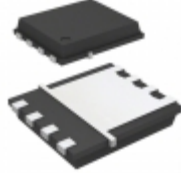
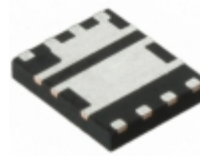

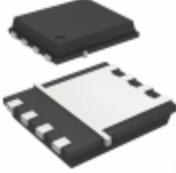
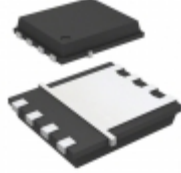

	<h2 style="color: red;">FDMS3672</h2> <p>Hersteller-Teilenummer: FDMS3672</p> <hr/> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 100V 7.4A POWER56-8</p> <hr/> <p>Datenblätter:  FDMS3672.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 22124 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FDMS3672
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 100V 7.4A POWER56-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	22124 pcs Stock
Serie	UltraFET™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-PowerWDFN
Supplier Device-Gehäuse	Power56
Verlustleistung (max)	2.5W (Ta), 78W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	7.4A (Ta), 22A (Tc)
Rds On (Max) @ Id, Vgs	23 mOhm @ 7.4A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	44nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2680pF @ 50V
Antriebsspannung (Max Rds On, Min Rds On)	6V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)















FDMS3672 ist neu im Original, Suche FDMS3672 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FDMS3672 Fairchild/ON Semiconductor mit Garantie und Vertrauen.
Anfrage FDMS3672: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FDMS3686S Fairchild/ON Semiconductor MOSFET 2N-CH 30V 13A/23A 8-PQFN</p>	 <p>FDMS3686S AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 30V 13A/23A 8-PQFN</p>	 <p>FDMS4D0N12C AMI Semiconductor / ON Semiconductor PTNG 120V N-FET PQFN56</p>	 <p>FDMS3669S Fairchild/ON Semiconductor MOSFET 2N-CH 30V 13A/18A PWR56</p>
 <p>FDMS3668S AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 30V 13A/18A 8-PQFN</p>	 <p>FDMS4435BZ Fairchild/ON Semiconductor MOSFET P-CH 30V 9A POWER56</p>	 <p>FDMS4435BZ AMI Semiconductor / ON Semiconductor MOSFET P-CH 30V 9A POWER56</p>	 <p>FDMS3672 AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 7.4A POWER56-8</p>

heiße Teile

Mehr

 FDMS3604S	 FDMS3606AS	 FDMS3606AS	 FDMS3606S	 FDMS3606S
 FDMS3610S	 FDMS3610S	 FDMS3612	 FDMS3615S	 FDMS3615S
 FDMS3622S	 FDMS3622S	 FDMS3625S	 FDMS3626S	 FDMS3626S
 FDMS3627S	 FDMS3629S	 FDMS3660S	 FDMS3660S	 FDMS3662
 FDMS3662	 FDMS3664S	 FDMS3664S	 FDMS3668S	 FDMS3668S
 FDMS3672	 FDMS4435BZ	 FDMS4435BZ	 FDMS5352	 FDMS5352
 FDMS5672	 FDMS5672	 FDMS6673BZ	 FDMS6673BZ	 FDMS6674BZ
 FDMS6681Z	 FDMS6681Z	 FDMS6990S	 FDMS7556S	 FDMS7556S
 FDMS7558S	 FDMS7558S	 FDMS7560S	 FDMS7560S	 FDMS7570S
 FDMS7570S	 FDMS7572S	 FDMS7572S	 FDMS7578	 FDMS7578

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